



Exploring Moiré Interferometry as a Tool to Measure Strain in the Silicon Anode of a Lithium Ion Battery

ECS PRiME Fall 2020: October 4th – October 9th 2020

Poster Presentation: A02-0265

Josefine McBrayer,^{1,2} Christopher Apblett,² Darwin Serkland,² Kyle Fenton,² and Shelley Minter¹

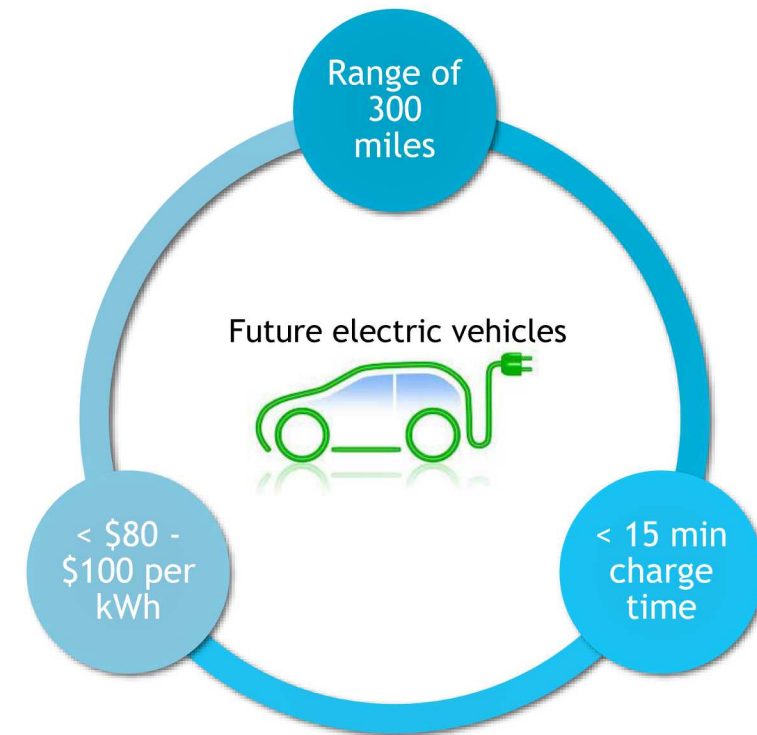
University of Utah,¹ Sandia National Laboratories²



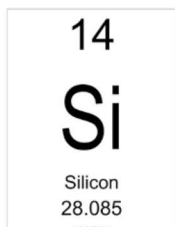
Importance of Lithium Ion Batteries



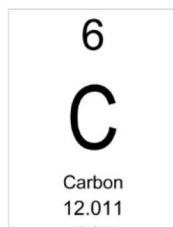
- Widespread use in personal electronics
- Part of the United States Vehicle Technology Office's goals for electric vehicles
- Current lithium ion battery energy densities are limited by the anode material



Silicon Anodes in Lithium Ion Batteries



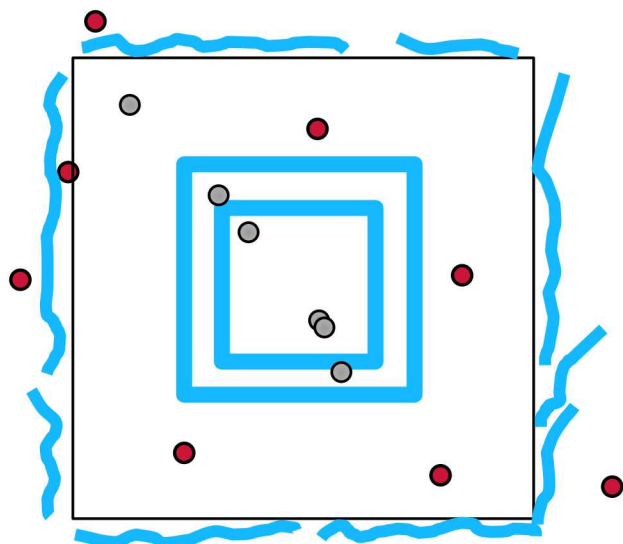
vs.



Lithium storage

□ 4.4 Li atoms per Si

□ 0.17 Li atoms per C



Silicon

3,579 mAh/g

● > 300% expansion



Graphite

372 mAh/g

Over 300% expansion upon lithiation
Unstable solid electrolyte interphase (SEI)

- Carbon
- Lithium
- Silicon



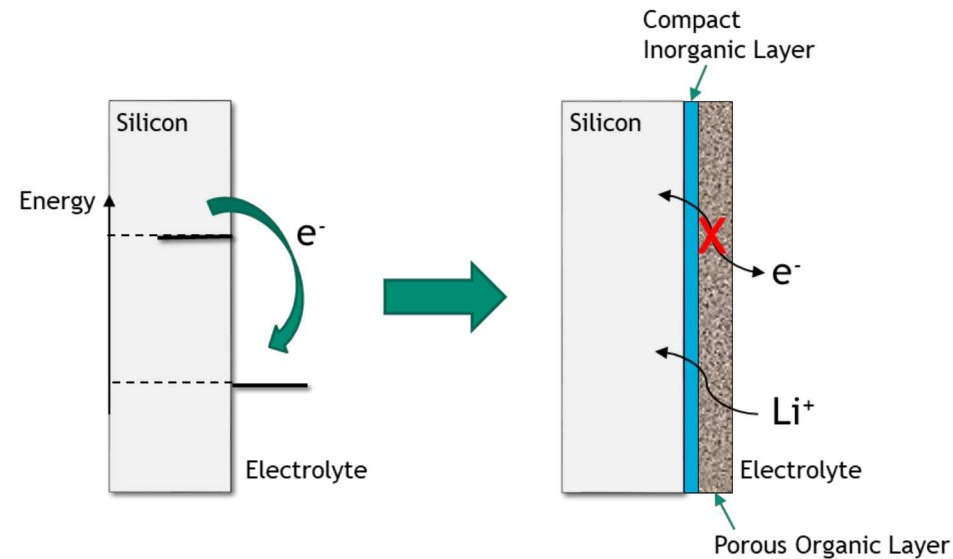
High specific energy
Long cycle life
Low self discharge

Solid Electrolyte Interphase

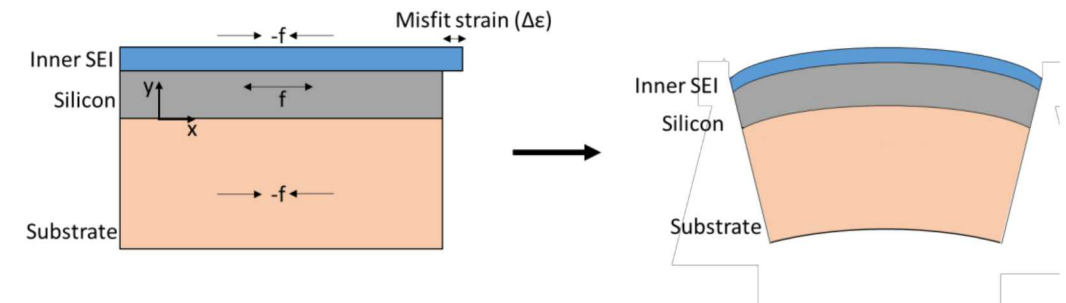
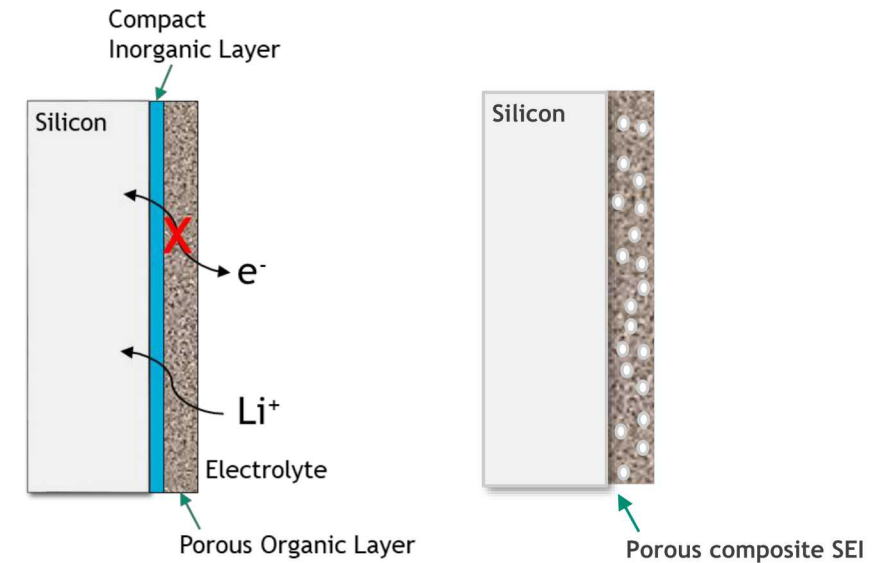


- Solid electrolyte interphase (SEI): passivating film that forms on the anode of the battery due to the reduction of the electrolyte
 - Ideally, lithium ions can pass through the SEI while electrons cannot
- The SEI on silicon degrades mechanically and chemically resulting in poor battery performance

Formation of the SEI due to the reduction of the electrolyte



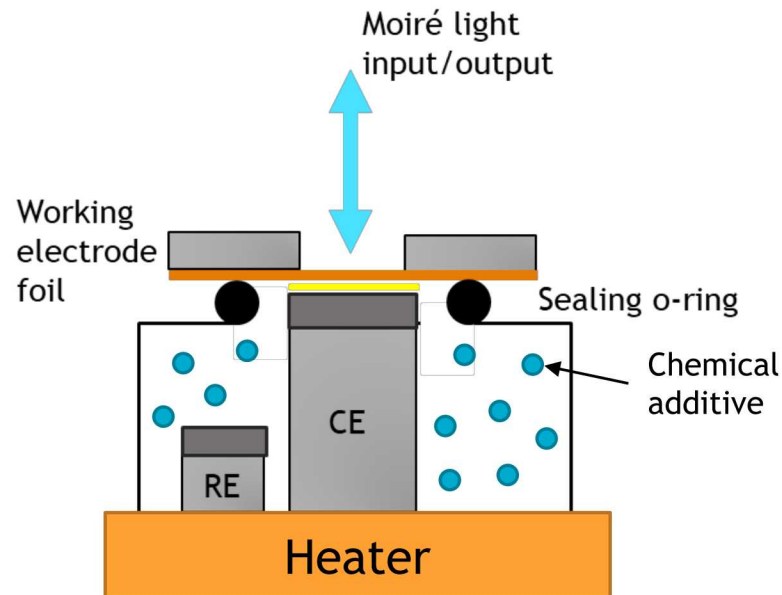
- The SEI failure mechanism has not been proven directly
 - Is the current two layer model correct?
- Constraint of the thin film from the current collector drives the stress response, but thin films allow for simpler mechanical analysis
- A common assumption/observation in literature is that silicon expansion as the silicon is lithiated, occurs only in z-direction for thin films
- This won't necessarily be the case as we move towards slurry systems
 - Can we keep a simplified system to study the SEI while preventing or decreasing constraint from current collector for comparison purposes?



Approach Explored

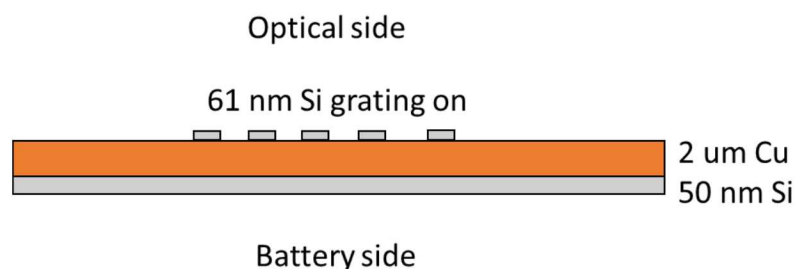


- By decreasing the thickness of the substrate/current collector, is it possible to more clearly observe strain from the back-side of the current collector due to the SEI?
- Can we develop the ability to see small changes in the strain due to changes in the SEI while maintaining a simplified thin film system?
 - Additives, temperature, initial exposure to electrolyte, etc.
- Can we study the in-plane strain change due to SEI prior to lithiation while out of plane changes will dominate during lithiation



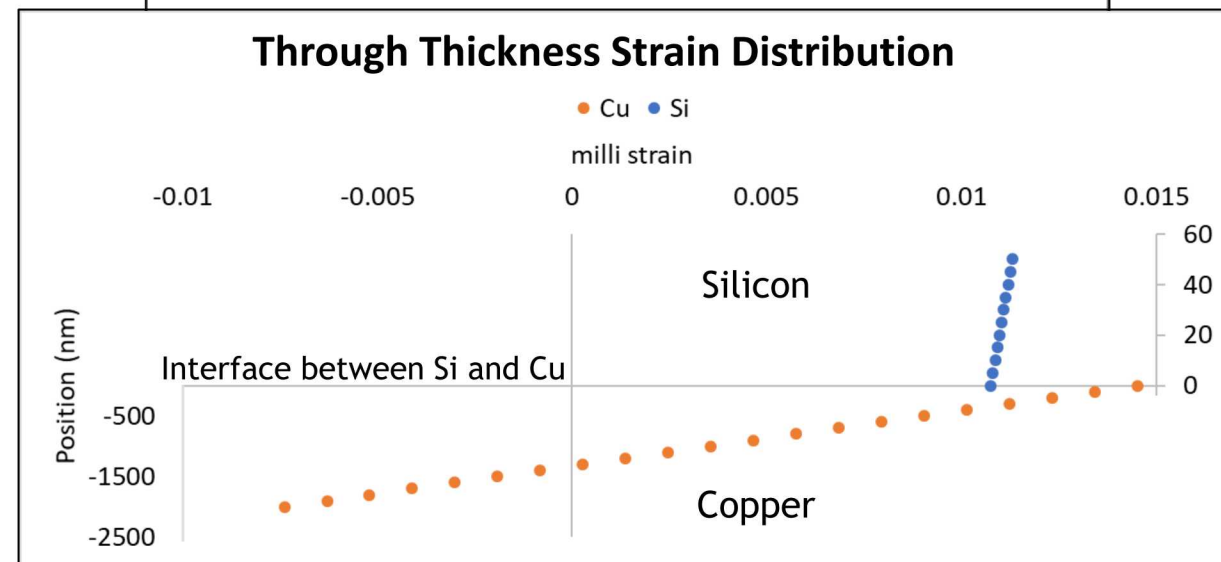
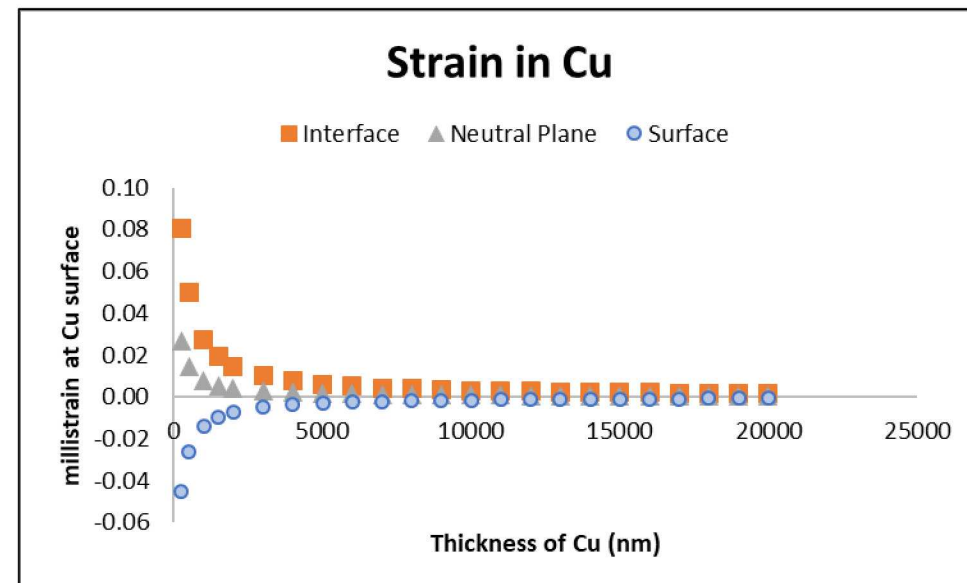
Thin Film Theory: Copper as a Substrate

- What level of resolution is required for a back-side technique to be able to see changes due to the SEI?
- With 2 μm thick copper, expect ~ 10 ppm, with 500 nm thick copper, expect ~ 35 ppm strain

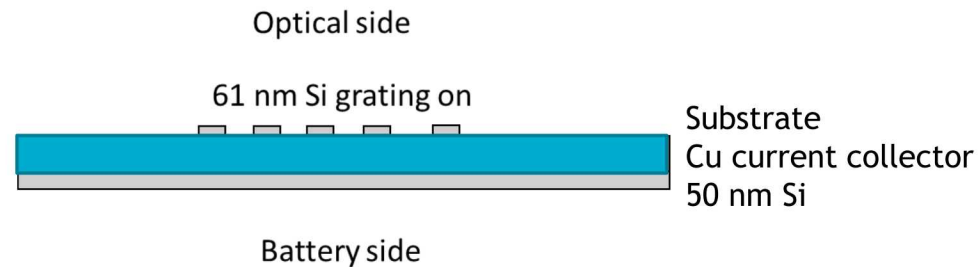


Parameters:

misfit strain ($\Delta\epsilon$)	0.01
E, silicon (GPa)	90
E, Cu (GPa)	128
E, SEI (GPa)	5
h, SEI (nm)	20
H1, silicon (nm)	50
H2, Cu (nm)	2000



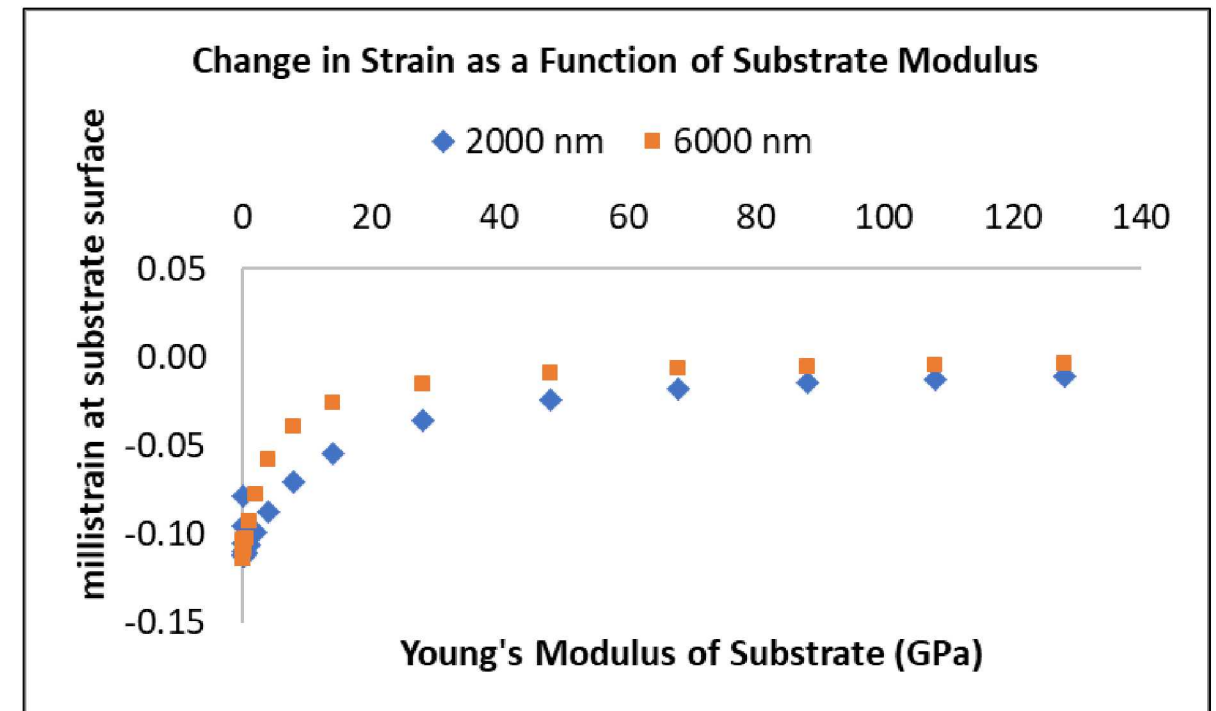
- Alternatively, the substrate modulus can be decreased to enhance the strain observed on the back-side of the electrode



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$$\kappa = \frac{6E'_s E'_f (h_f + h_s) h_f h_s \Delta\epsilon}{E_f'^2 h_f^4 + 4E'_s E'_f h_f^3 h_s + 6E'_s E'_f h_f^2 h_s^2 + 4E'_s E'_f h_f h_s^3 + E_s'^2 h_s^4}$$

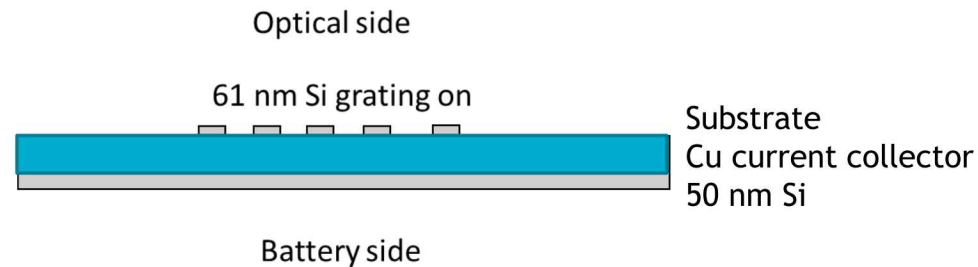


Thin Film Theory: Changing the Modulus of the Substrate



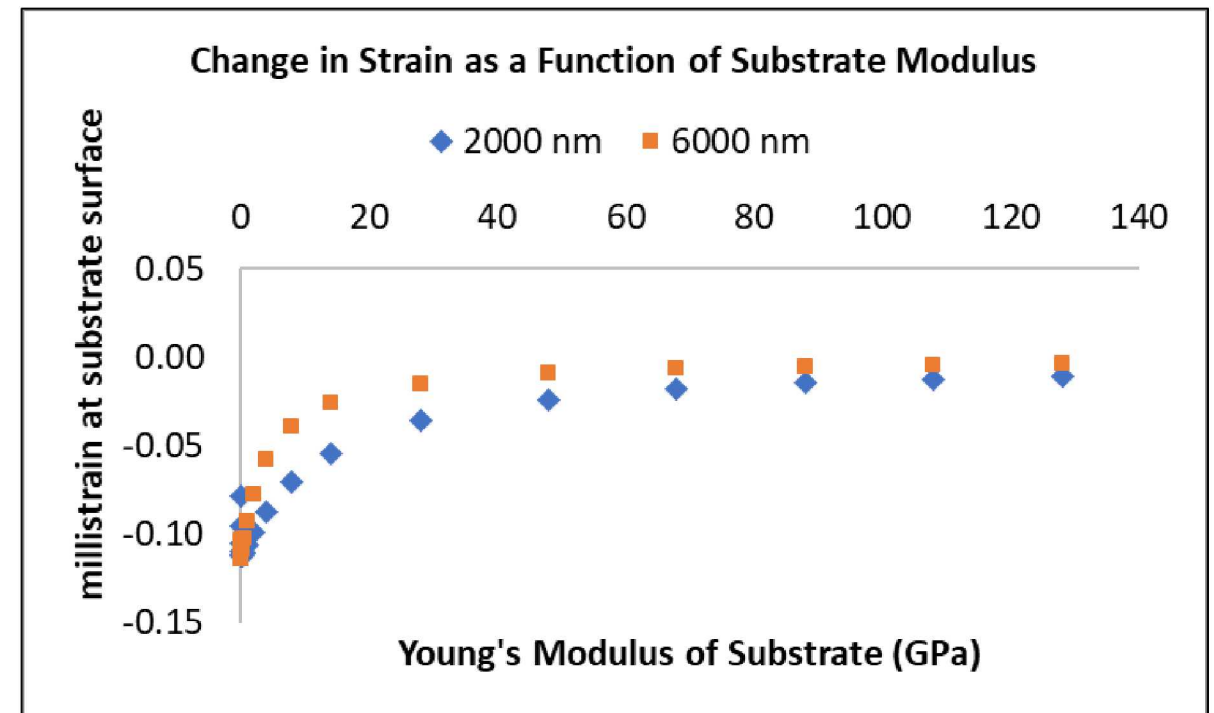
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Improving sensitivity to back-side measurements can be achieved by using a thinner substrate and is furthered by decreasing substrate modulus



Parameters:

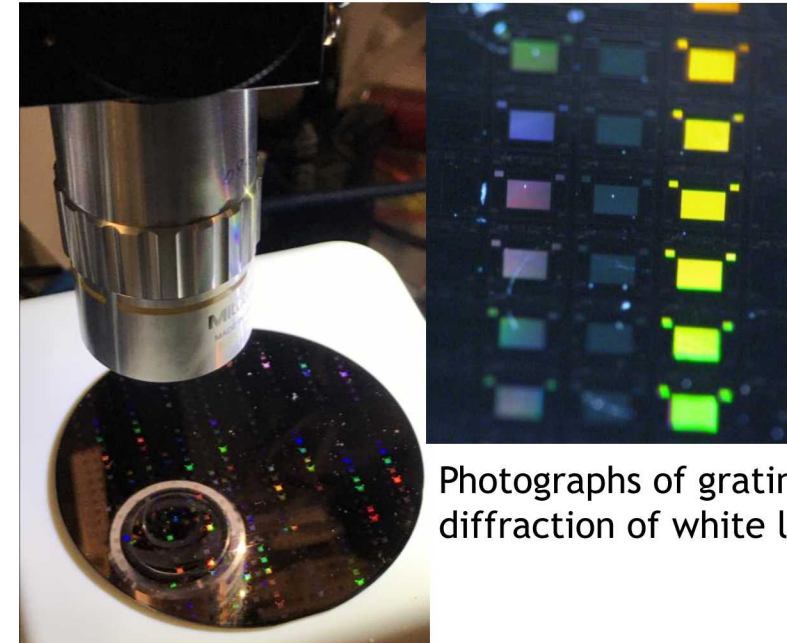
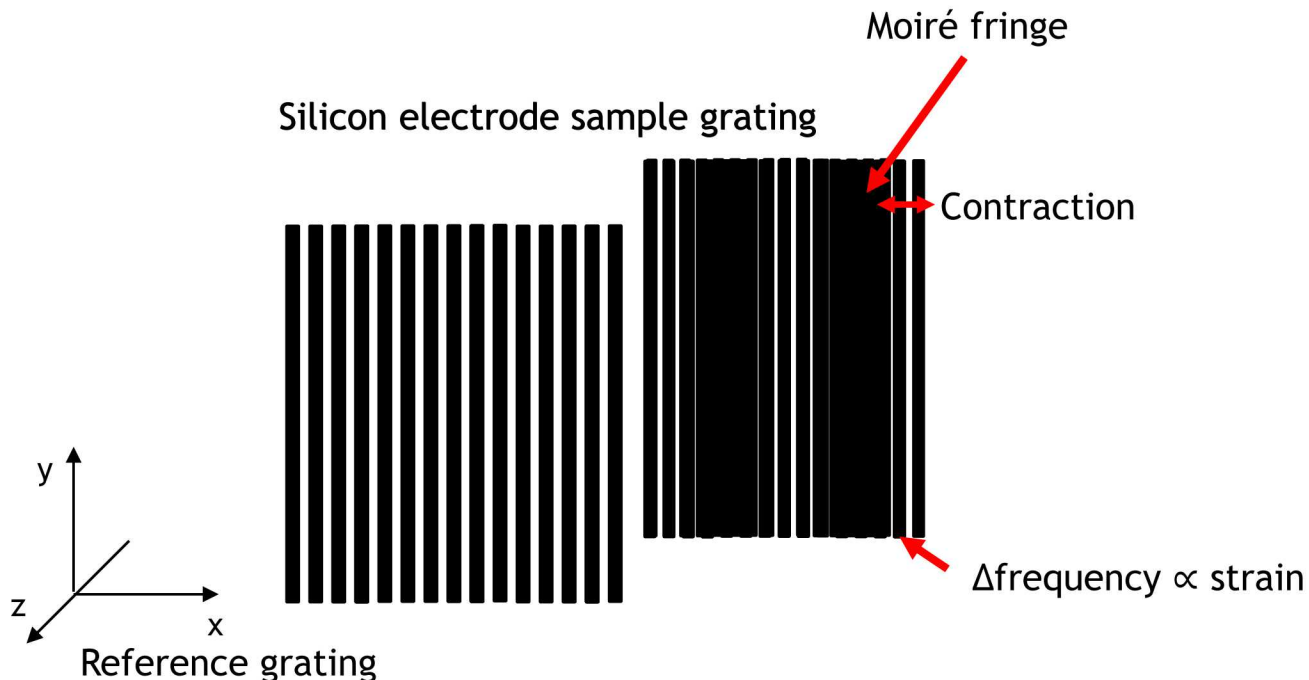
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How Moiré Microscopy Works



- Moiré fringes are formed when two similar gratings are overlaid and are offset
- Why use moiré microscopy?
 - Minimal change to the system
 - Simple instrumentation
 - Direct measurement of in-plane strain as compared to curvature measurements
 - Strain resolution beneath the diffraction limit of light

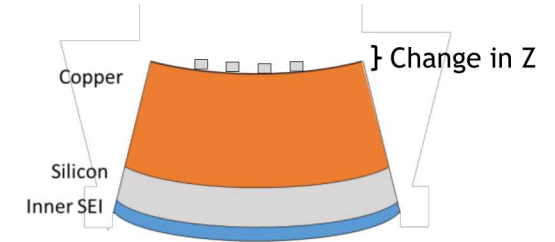


Photographs of gratings showing diffraction of white light

How Moiré Microscopy Works



- In this presentation, Z focus will be discussed
 - Synonymous terms: focus, Z position
- Z position is the direction normal to the sample surface
- A change in focus is expected
 - Thin membrane, gassing during SEI formation, curvature due to stress



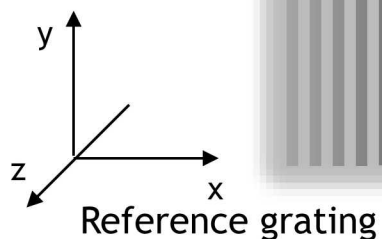
Effect of focus on moiré

Silicon electrode sample grating

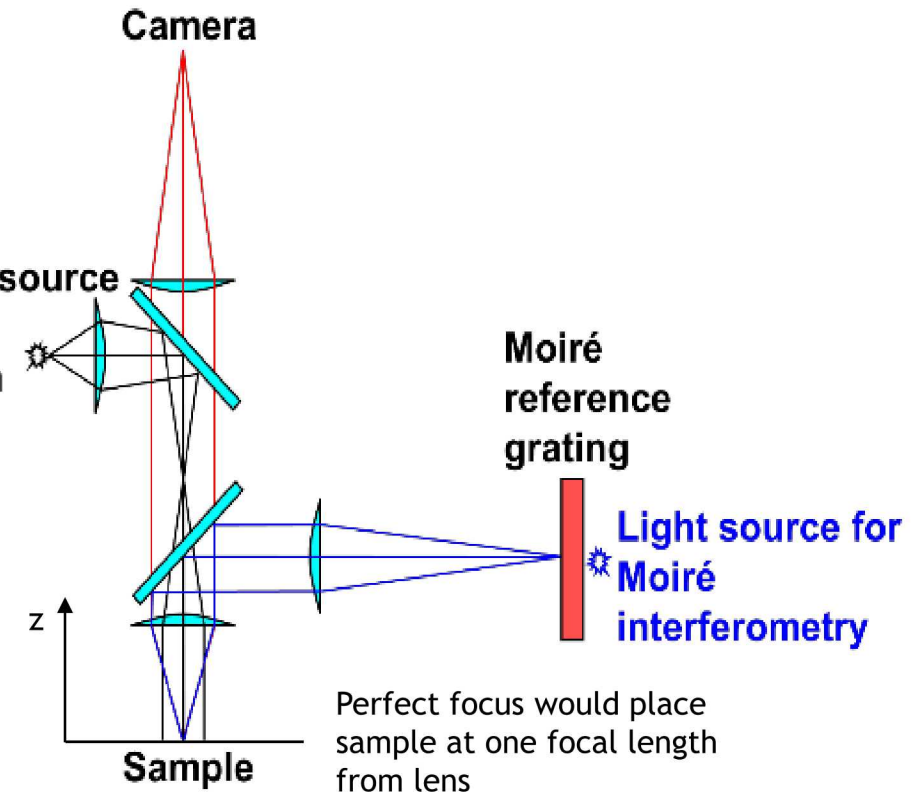
Moiré fringe

Contraction

$\Delta \text{frequency} \propto \text{strain}$
 $\Delta \text{frequency}$ should remain the same with increased noise

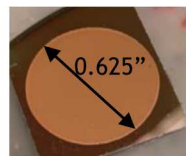


White light source
for Köhler
illumination



Perfect focus would place
sample at one focal length
from lens

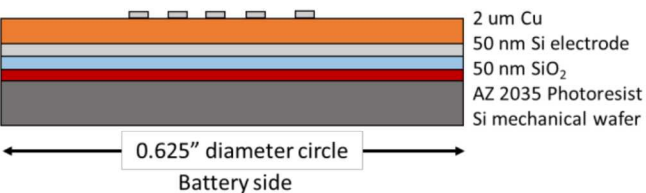
Experimental Setup



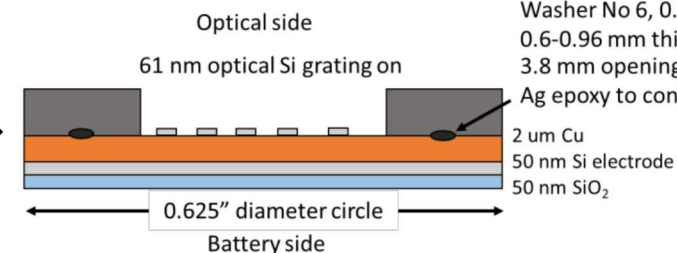
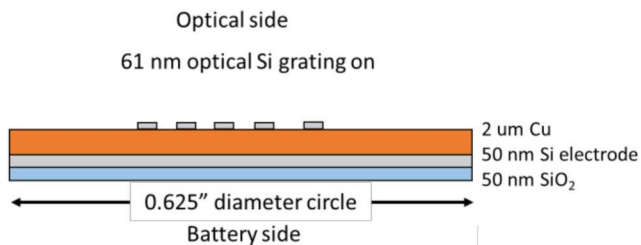
Optical side
61 nm optical Si grating on

Cu side with grating post-release

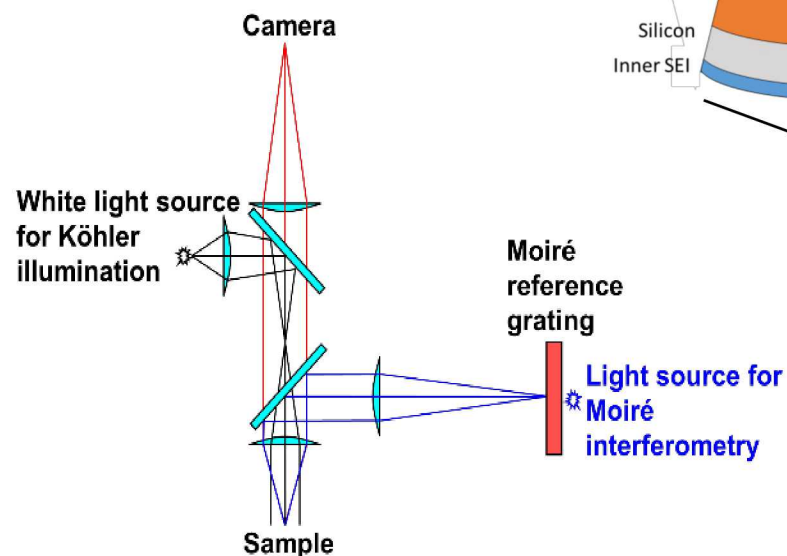
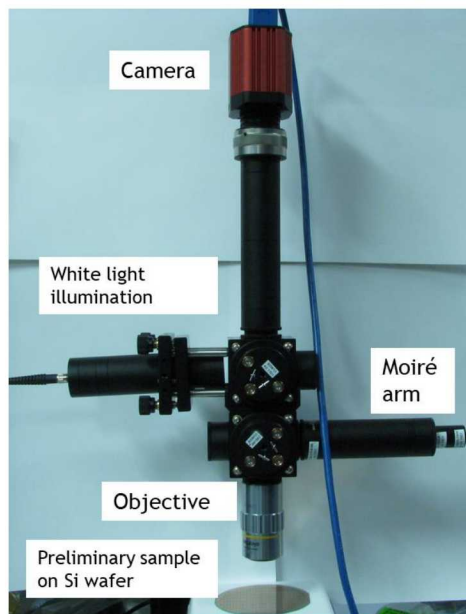
Washer No 6, 0.625 in diameter
0.6-0.96 mm thick
3.8 mm opening in washer
Ag epoxy to connect washer



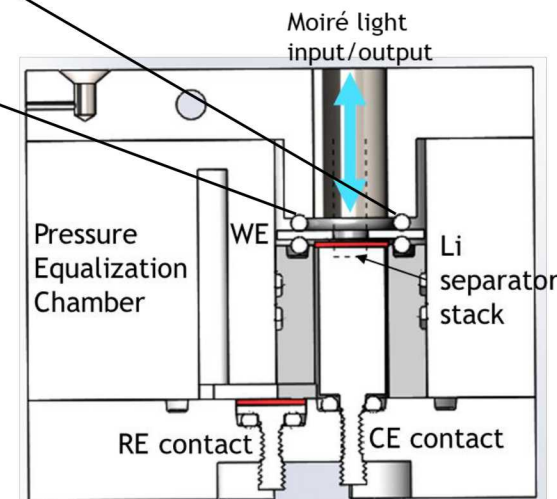
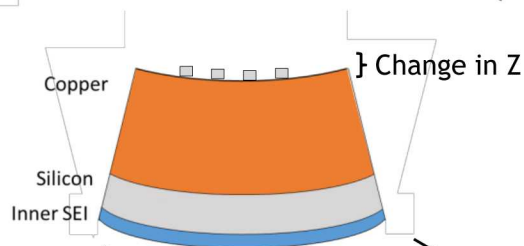
Schematic of foil electrode pre-release



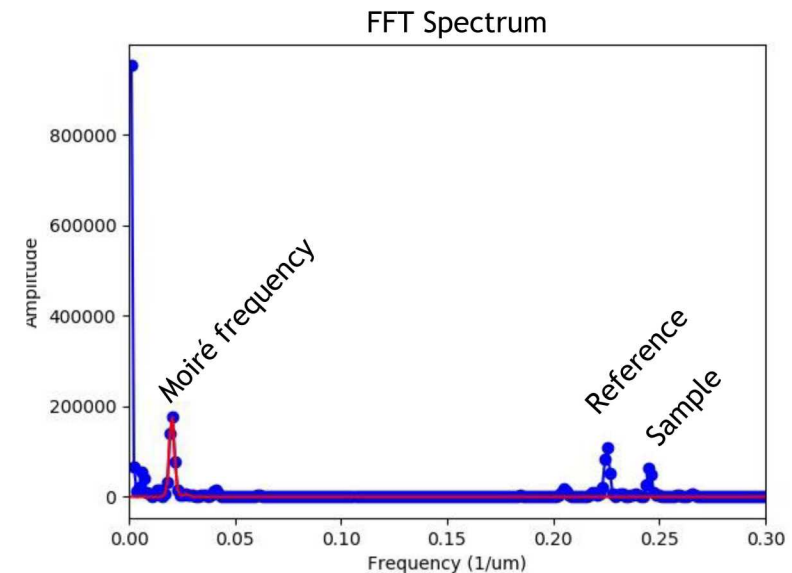
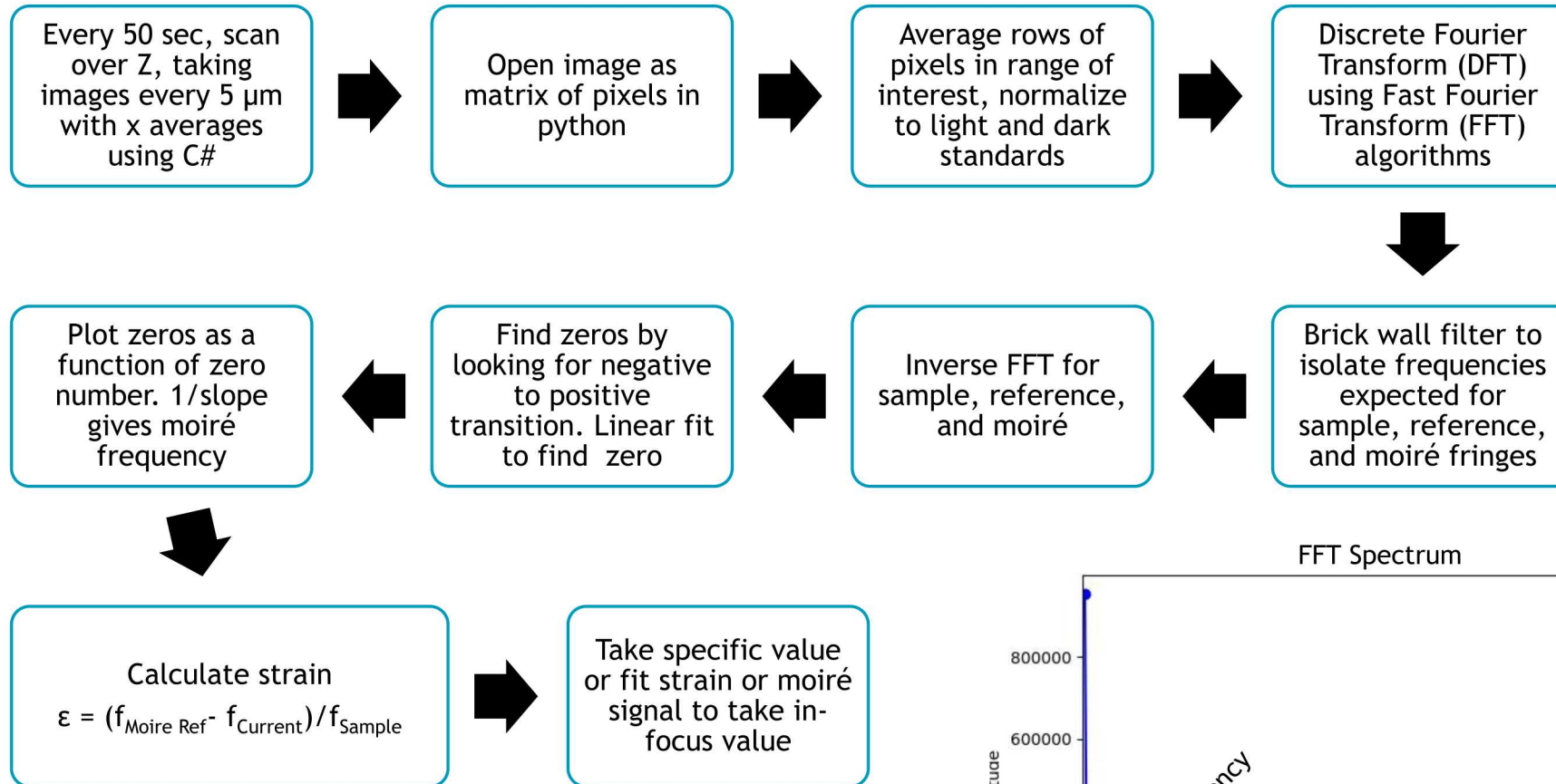
O₂ plasma clean and removal of SiO₂ with HF (little to no native oxide)

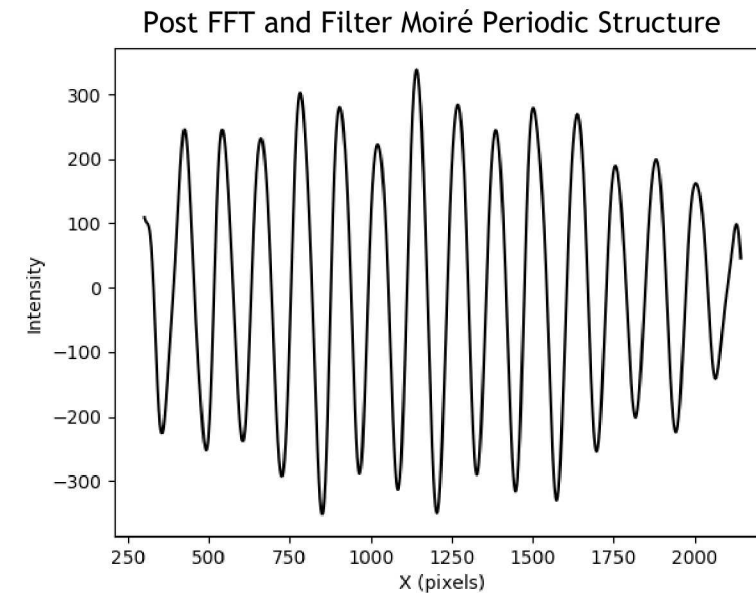
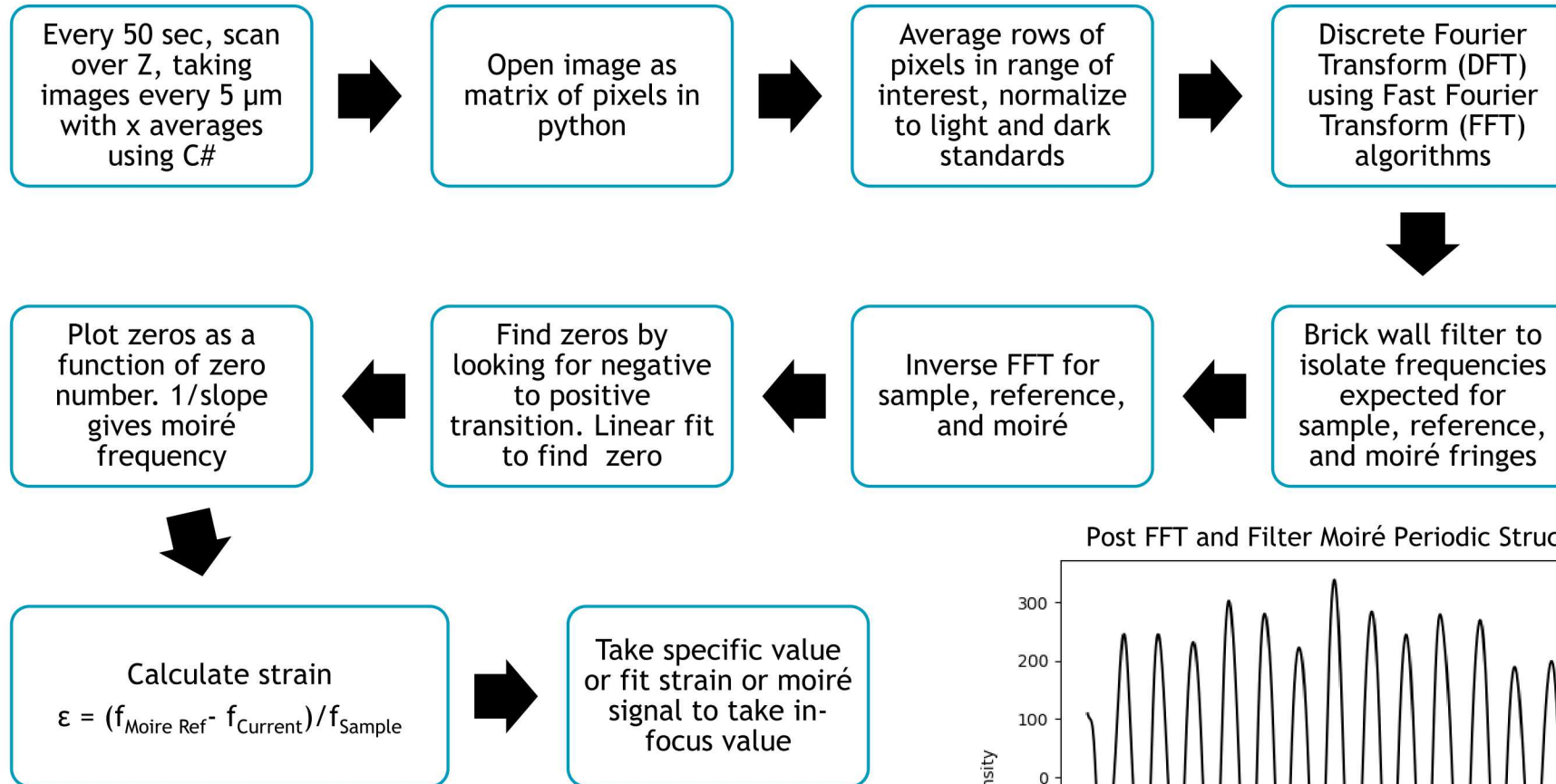


Schematic of the moiré microscope



Time sensitive transfer of sample and building of cell (in glovebox within ~10 min and built within the hour)

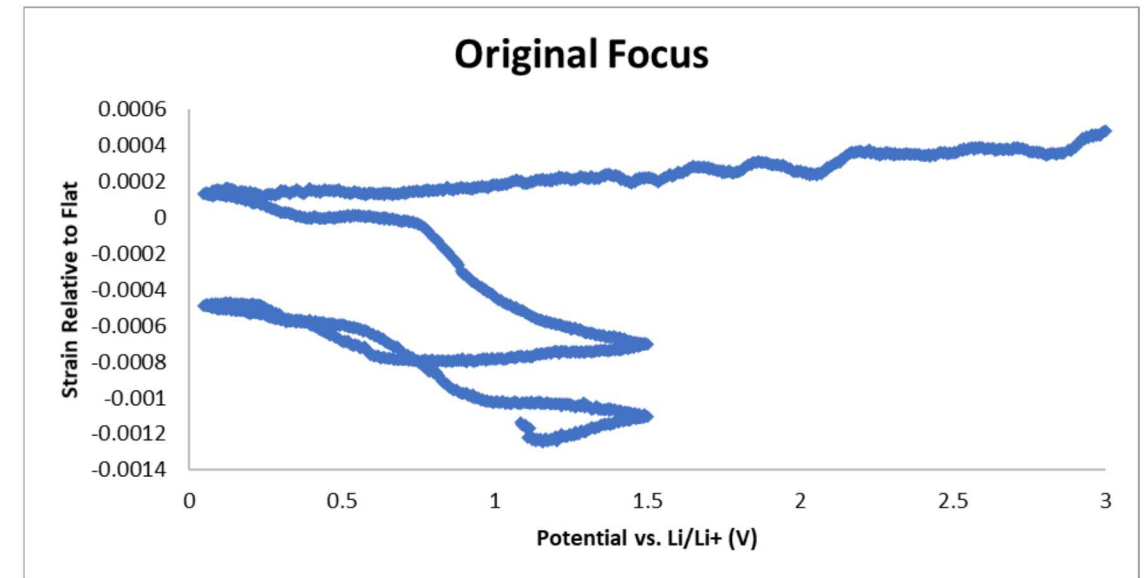
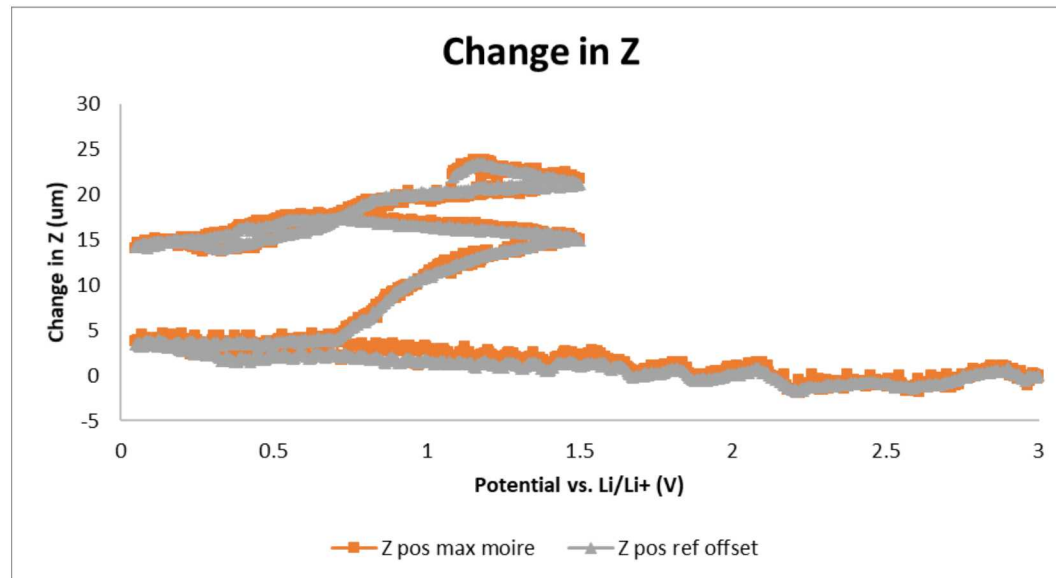




First Setup was not Insensitive to Focus Position



- Observed “strain” was erroneous and tracked perfectly with changes in Z during cycling



Old Setup: Structured Illumination for Reference



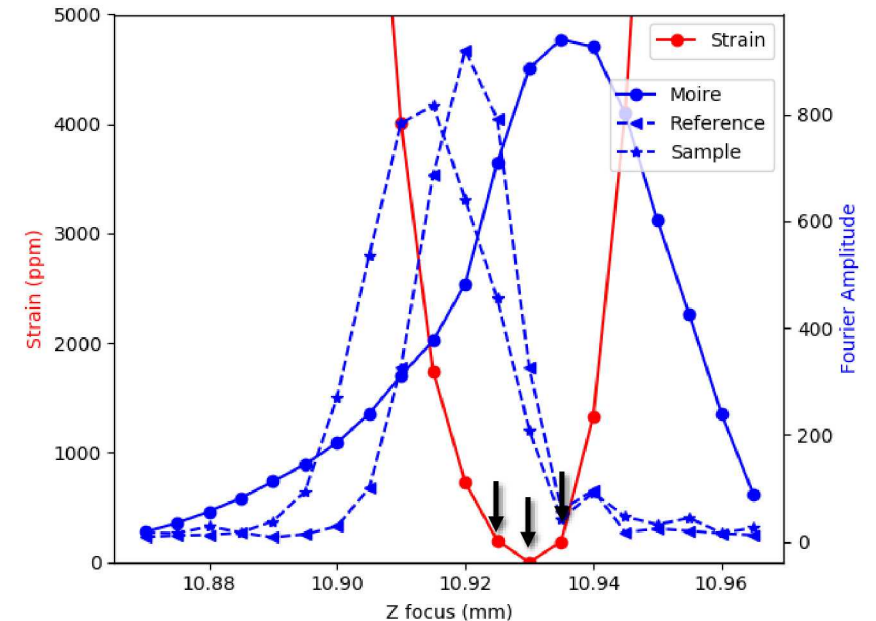
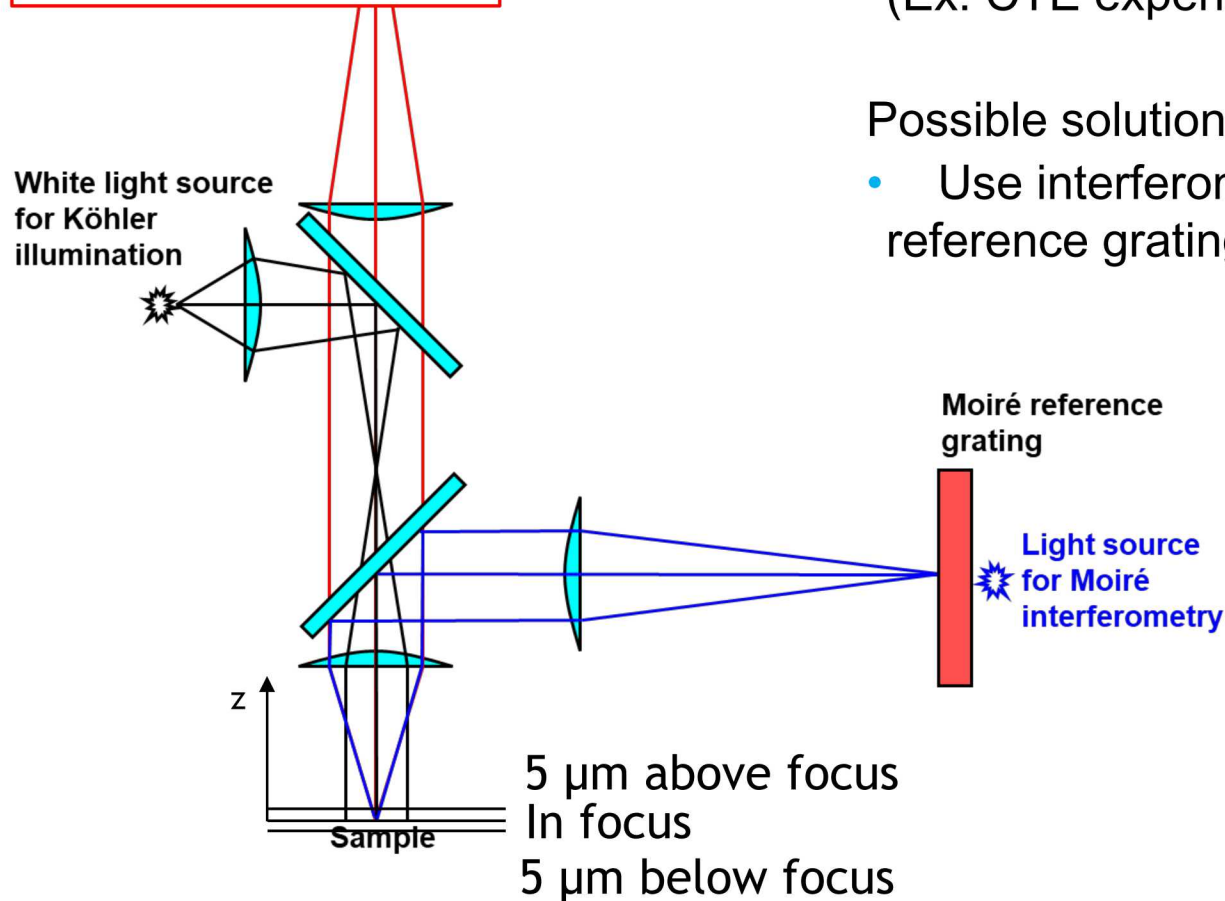
Over 200 ppm of strain change when move 5 μm out of focus when looking for 35 ppm change in strain

PROBLEM:

- Strain changes drastically as a function of Z position
- Noisy and hard to reproduce
- Can get consistent data on static sample, but as soon as it moves in Z (Ex. CTE experiment) cannot get consistent data

Possible solution:

- Use interferometry rather than structured illumination to create the reference grating

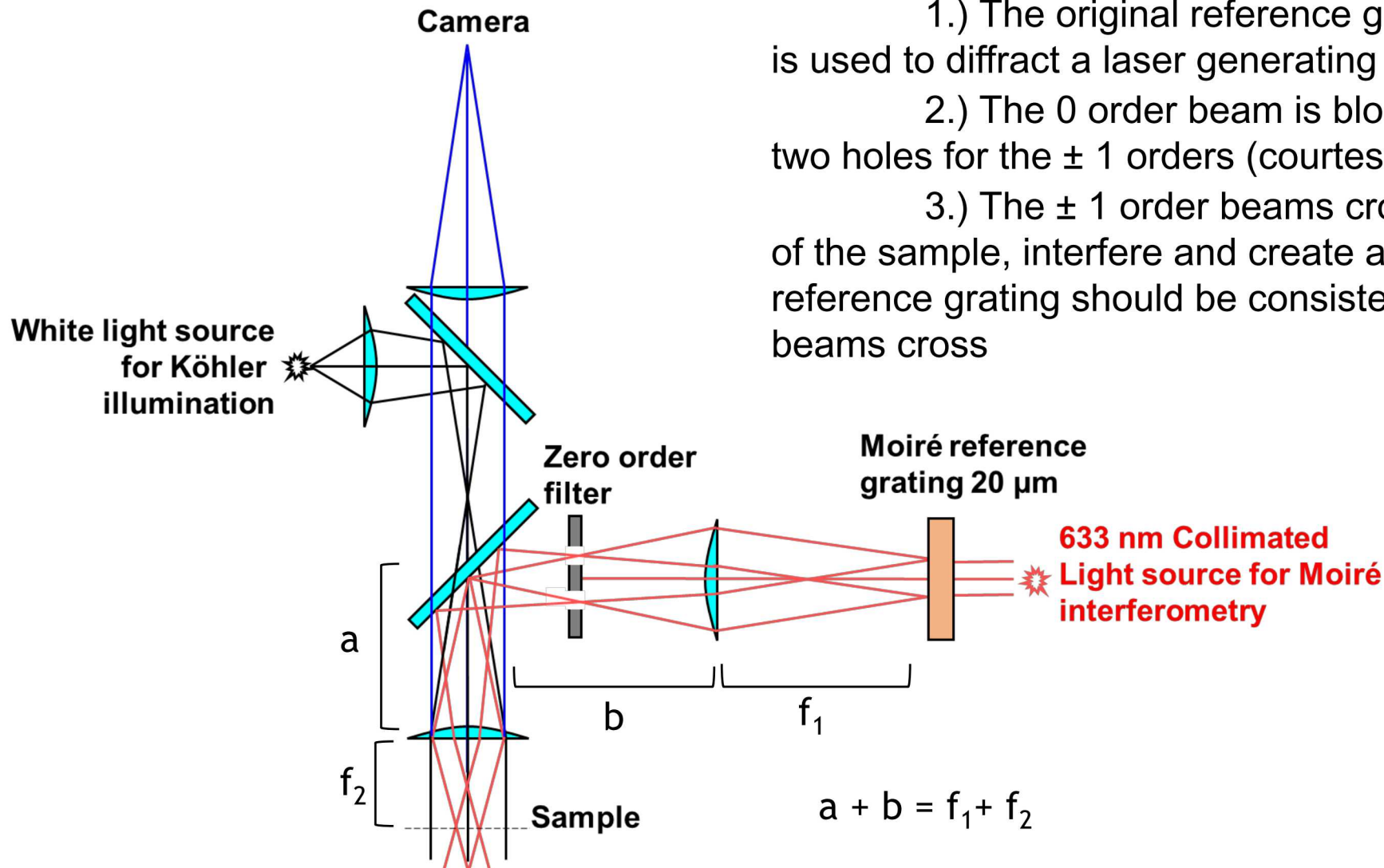


New Setup: Interference of ± 1 Orders for Reference



Method:

- 1.) The original reference grating from the previous setup is used to diffract a laser generating 0 and ± 1 orders
- 2.) The 0 order beam is blocked by a 3D printed filter with two holes for the ± 1 orders (courtesy of Ted Morin)
- 3.) The ± 1 order beams cross each other near the plane of the sample, interfere and create a reference grating. The reference grating should be consistent over region that the two beams cross



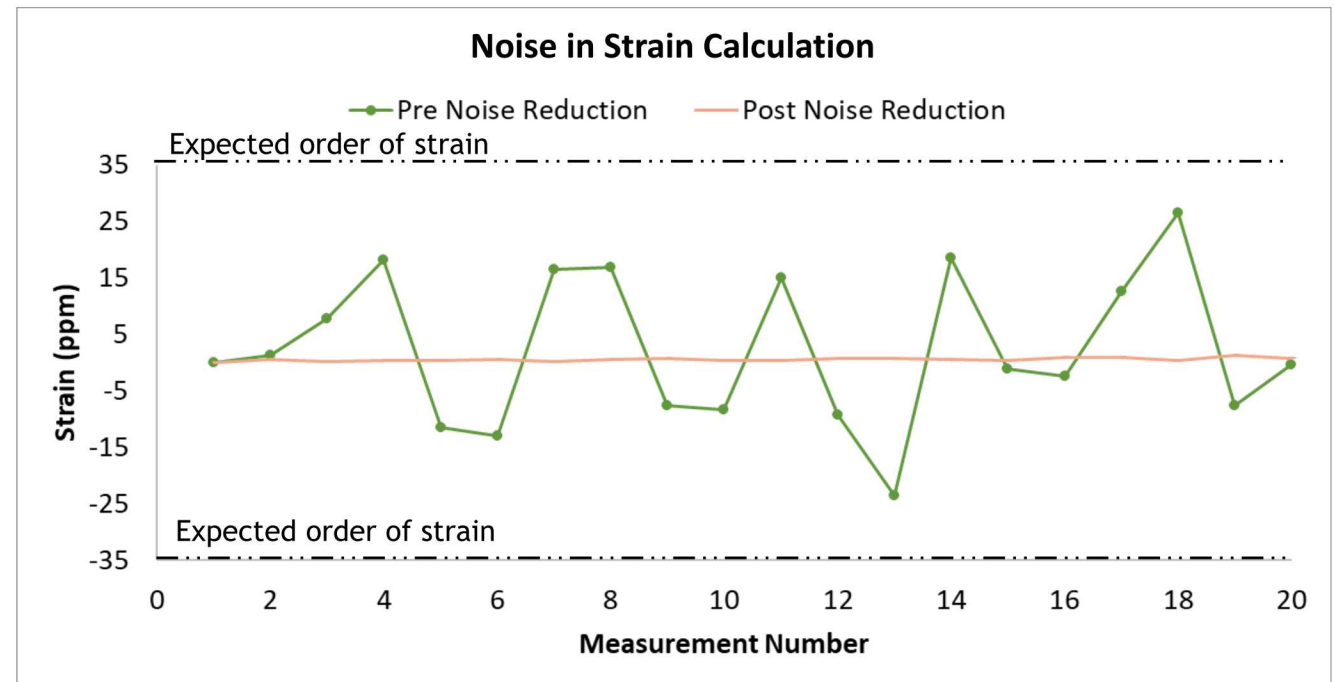
$$f_1 = 80 \text{ mm}$$

$$f_2 = 35 \text{ mm}$$

Noise in Static Imaging Reduced



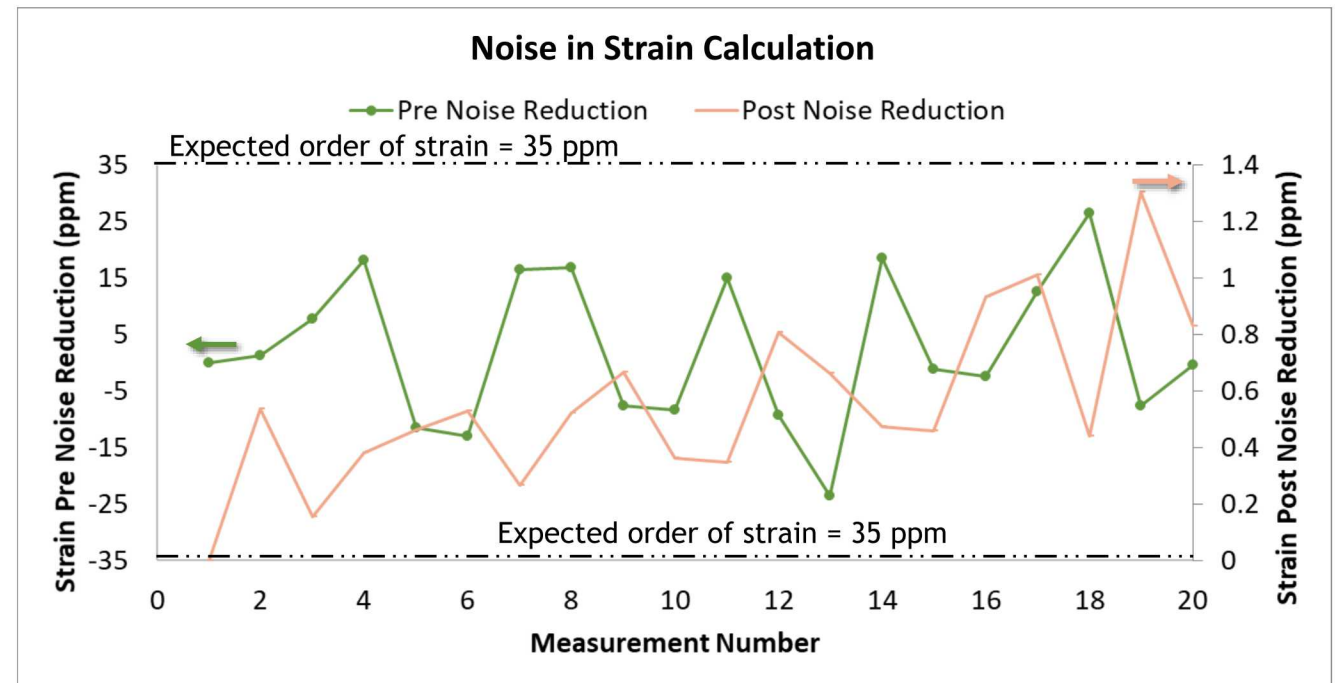
- Noise was on the order of the measurement we are expecting to make – on order of 50 ppm of strain
- Have decreased noise in static imaging to less than 2 ppm
 - Increased averaging
 - Changing to a monochromatic camera
 - Improving AR coating



Noise in Static Imaging Reduced



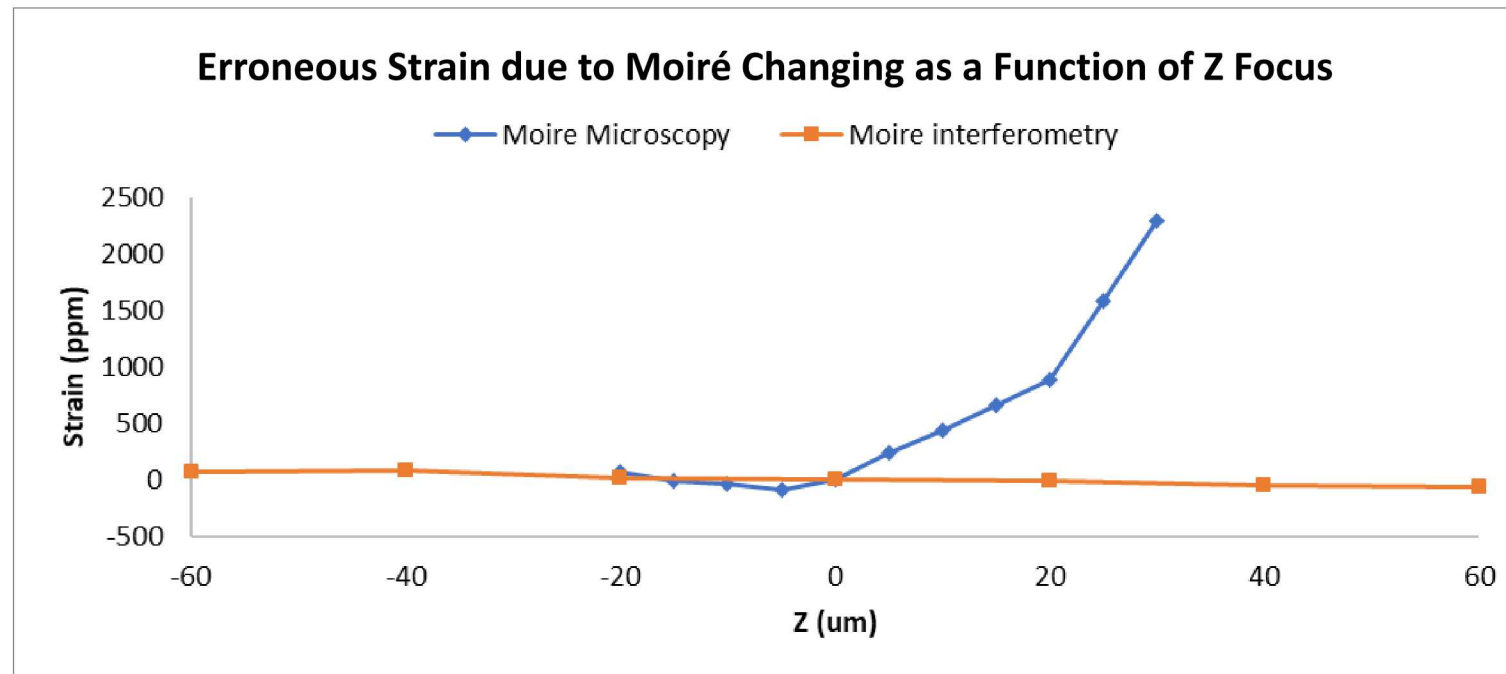
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Decrease in Z Sensitivity Achieved



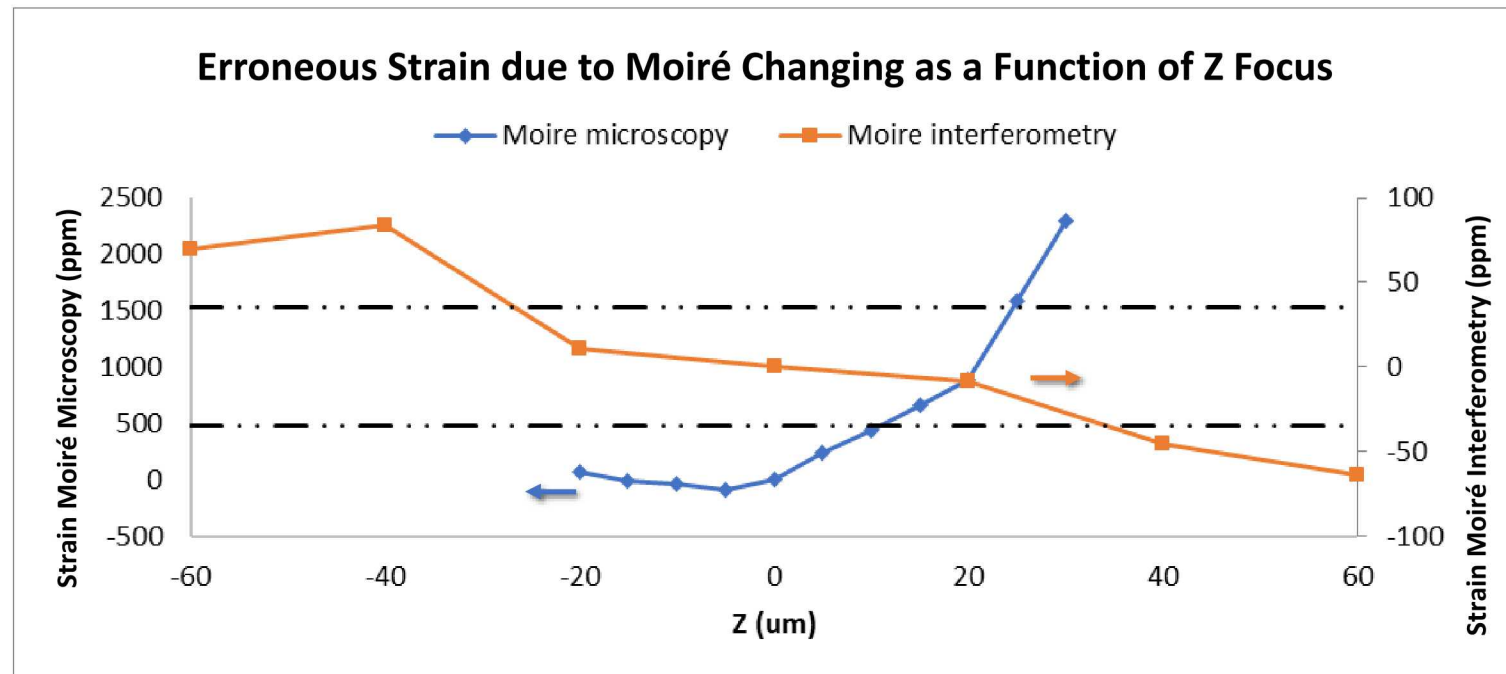
- Switching methods greatly reduced the effect of changes in Z
 - $\pm 30 \mu\text{m}$ change in Z before reach $\sim 35 \text{ ppm}$ of strain



Decrease in Z Sensitivity Achieved

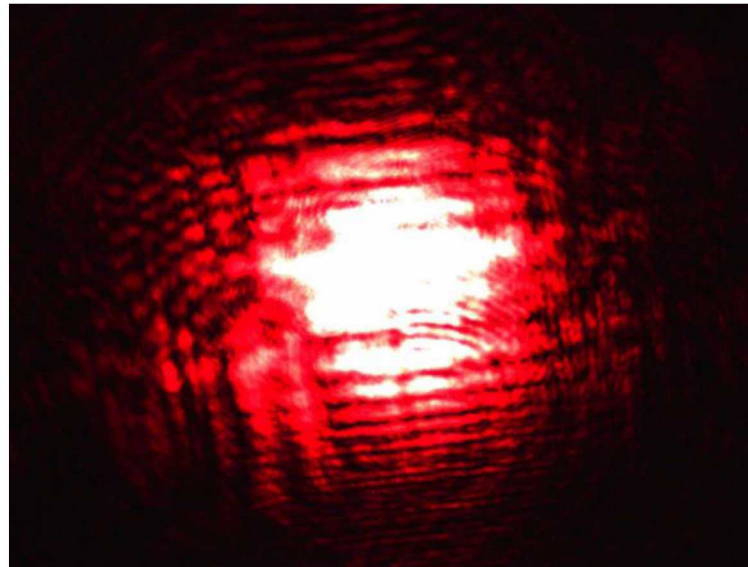


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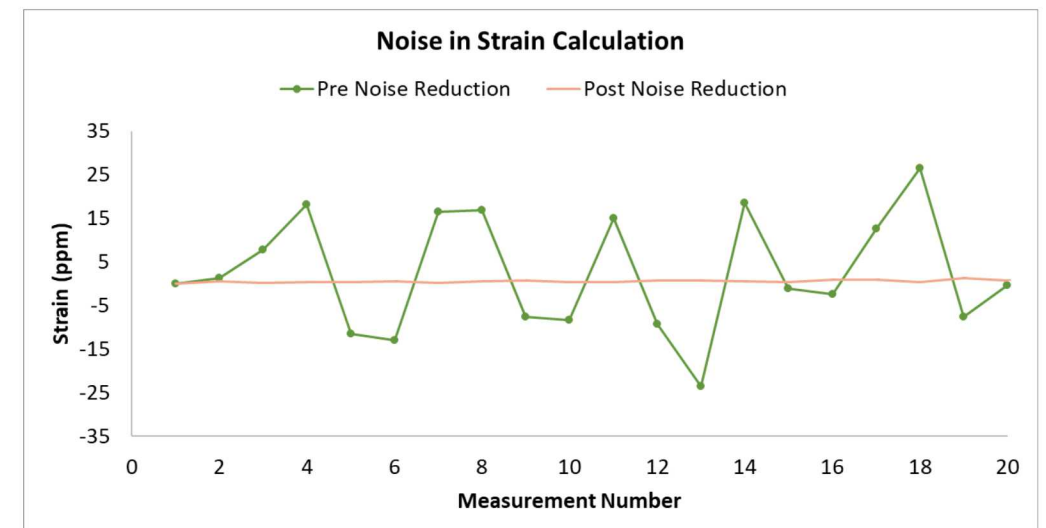
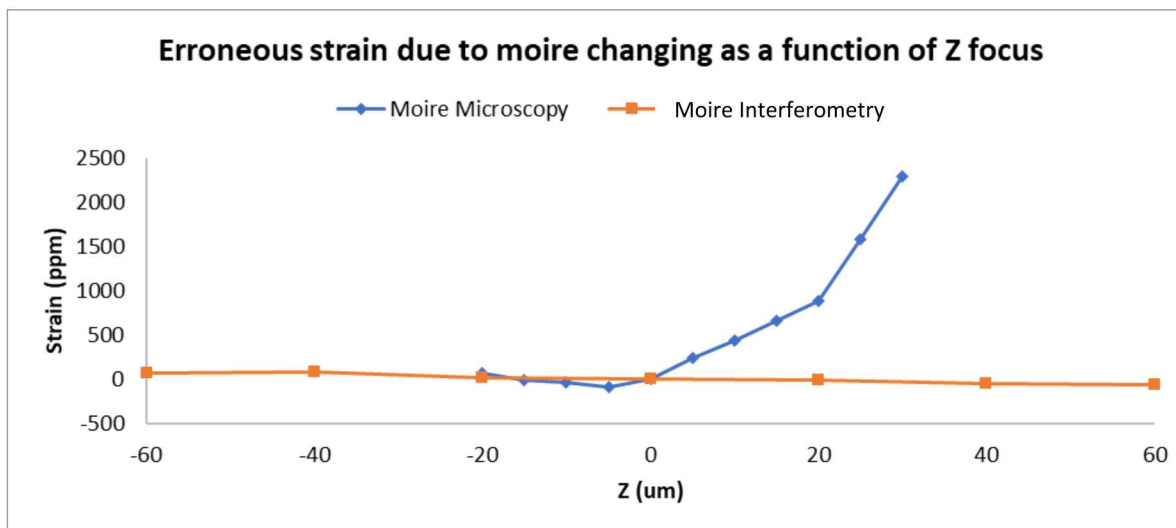


- Did achieve large decrease in Z sensitivity
- Now have sensitivity in tip/tilt of the sample which may be difficult to keep well aligned during an *in situ* test
 - Small instabilities could also be playing a role as observed during alignment of the microscope
 - Air currents, thermal fluctuations, vibrations, etc.

Alignment of Sample Tilt



- Determined previous *in situ* results to be incorrect because of convolution of the moiré signal due to changes in Z in addition to actual changes in strain
- Changed approach to moiré by forming a reference grating via interference rather than structured illumination
- Reduced noise in static imaging and reduced observed “strain” dependence on Z
- Future work
 - Use developed technique to measure high strain electrochemical processes
 - Despite improvements in noise and sensitivity to Z focus, keeping alignment during in situ operation is difficult, therefore new techniques will be explored



Thank you!



Solid electrolyte interphase stabilization (SEISta) research consortium and Vehicle Technologies Office

Dr. Shelley Minter and Minter research group at the University of Utah

Power Sources and Technology Group at Sandia National Laboratories

Dr. Kyle Fenton

Dr. Chris Appleby

Dr. Darwin Serkland

Dr. Chris Orendorff

Victoria Sanchez

My committee



Presenter:
Josefine McBrayer



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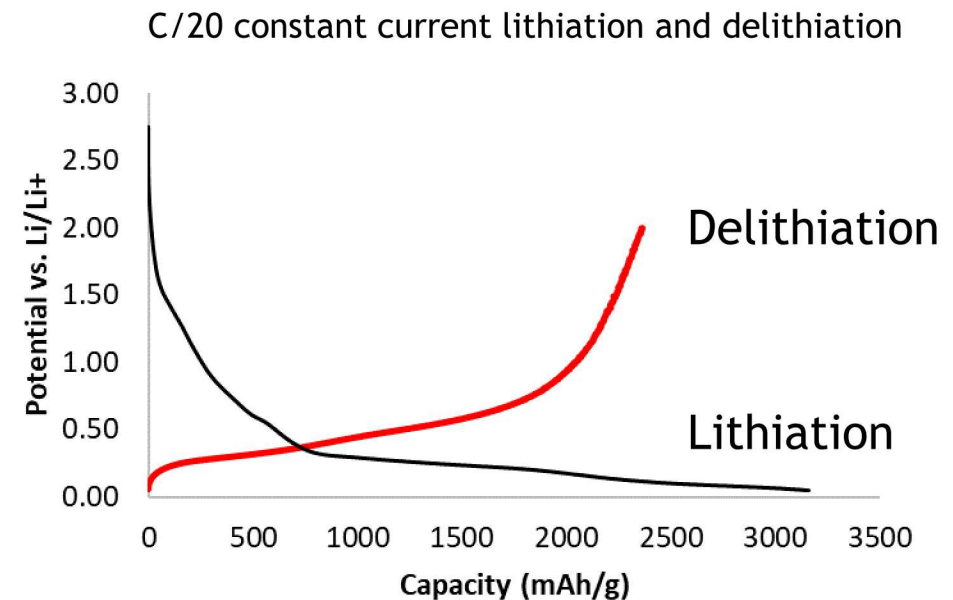
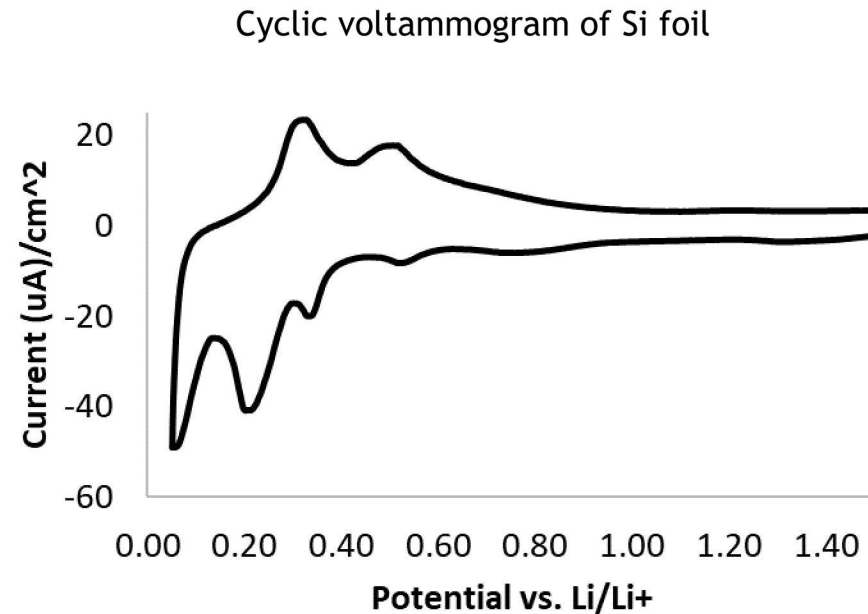
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Evaporated Foil Electrochemistry



Cyclic voltammetry and constant current discharge shows lithiation and delithiation of the silicon thin film on the evaporated foil electrode



Coin cell half cell configuration

WE: Si evaporated foil

CE/RE: Li metal

Electrolyte: 1.2 M LiPF_6 , 3:7 Ethylene carbonate: ethyl methyl carbonate

Scan rate: 0.1 mV/s

Environment: Built under argon, RT